



# Characterization of radiation-degraded SiPM with unresolved pulse height spectrum

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## ☐ Motivation:

- ◆ Unresolved photoelectron spectra are not very exotic
- ◆ SiPM characterization methods are not determined to find Gain, number of primary photoelectrons  $N_{pe}$ , ENF/probability of crosstalk CT

## ☐ Statistics of correlated events as a key of the problem:

### Branching Poisson process and Generalized Poisson distribution

- ◆ Model and its verification results
- ◆ CERN CMS SiPM characterization by Generalized Poisson

## ☐ Resolving unresolved by Effective Gain (Fano factor)

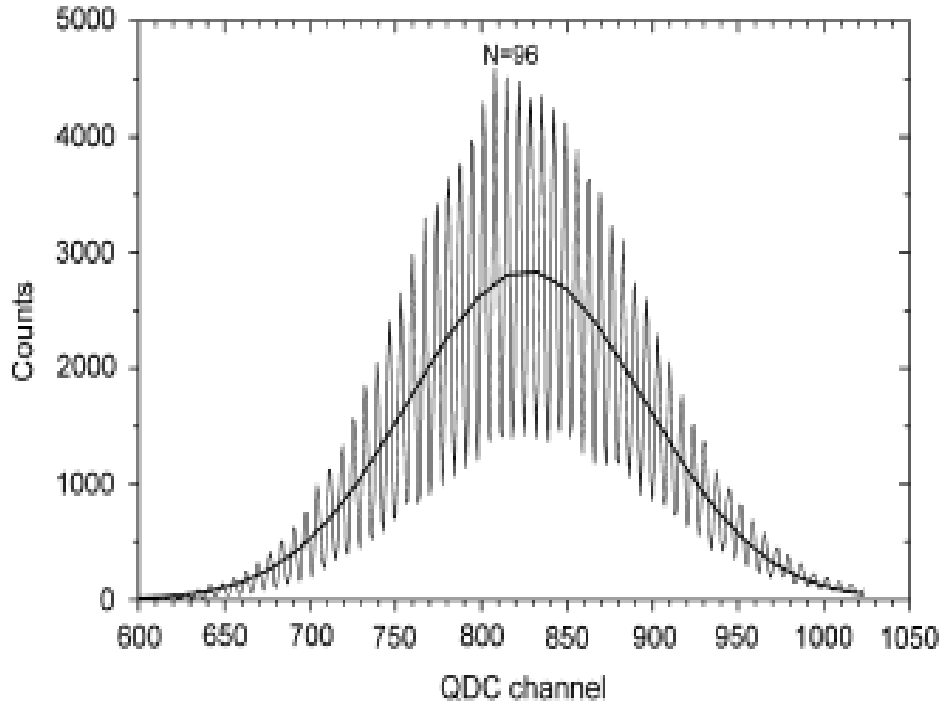
## ☐ Summary

# SiPM: photon number resolving detector



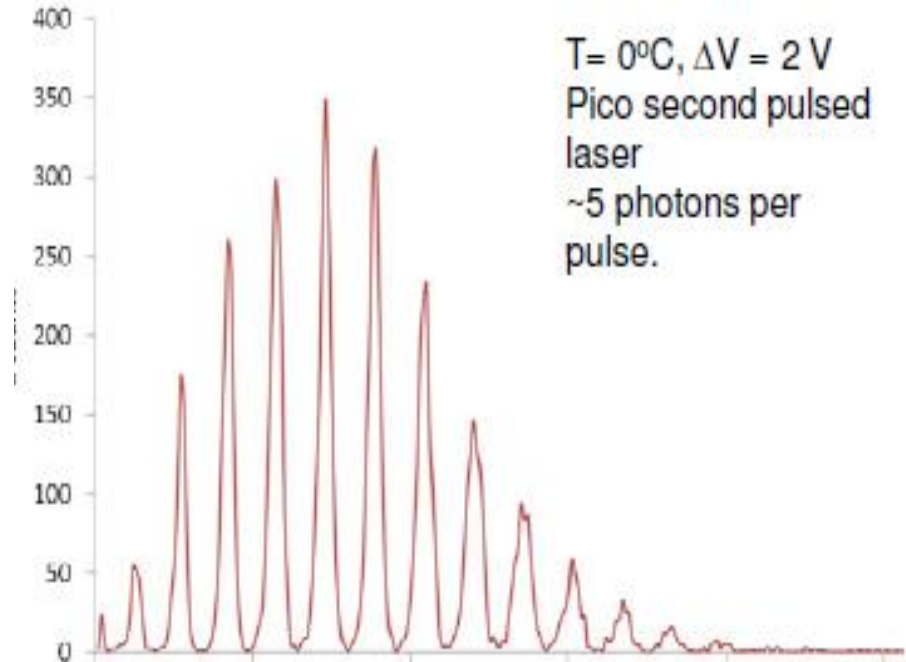
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SiPM (MEPhI / Pulsar)



R. Mirzoyan et al., NDIP, 2008

SiPM (Excelitas)



A. Barlow and J. Schilz, CERN, 2011

☐ Why we are concerned about unresolved SiPM spectra?

# Resolved spectrum = known Npe & Gain



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If the spectrum peaks are visible => Gain

If the zero-peak  $N(0)$  is determined and

if Poisson light is assumed => Npe

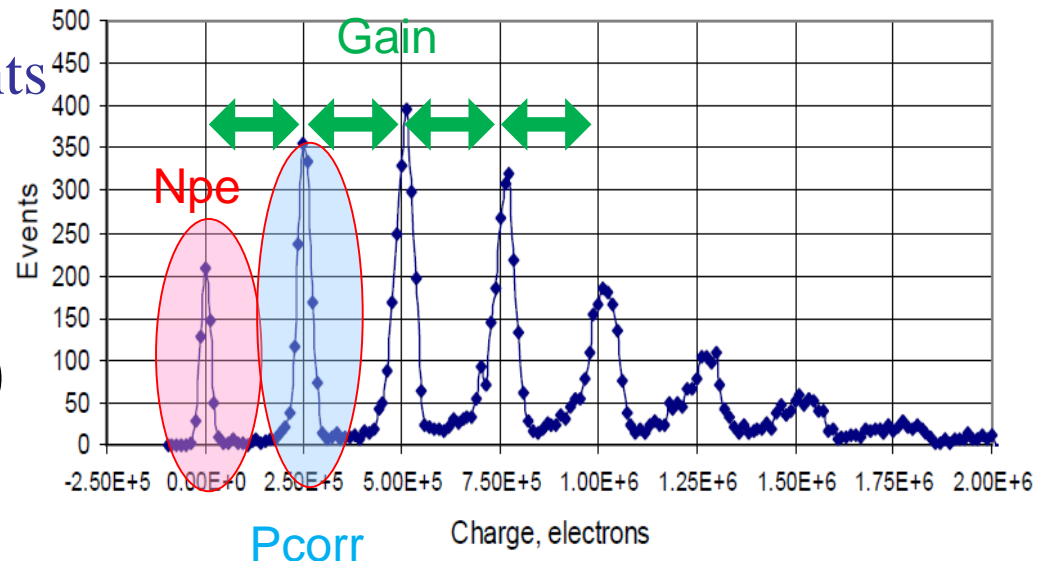
$$\Pr(0) = N(0)/N_{tot} = \exp(-N_{pe})$$

Probability of correlated events

$P_{corr}$  could be defined by  
deviation from Poisson:

$$P(N = 1) = P_{poisson}(N = 1) \cdot (1 - P_{corr})$$

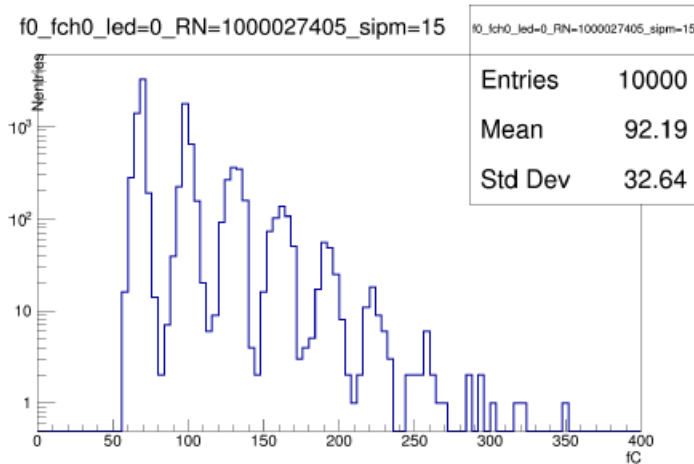
Output Charge Distribution Histogram  
for multiphoton pulse detection



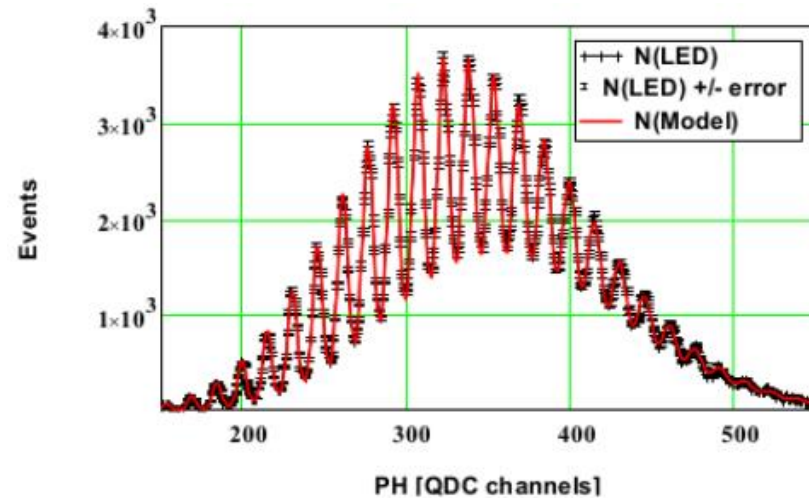
# 1. Large signal detection



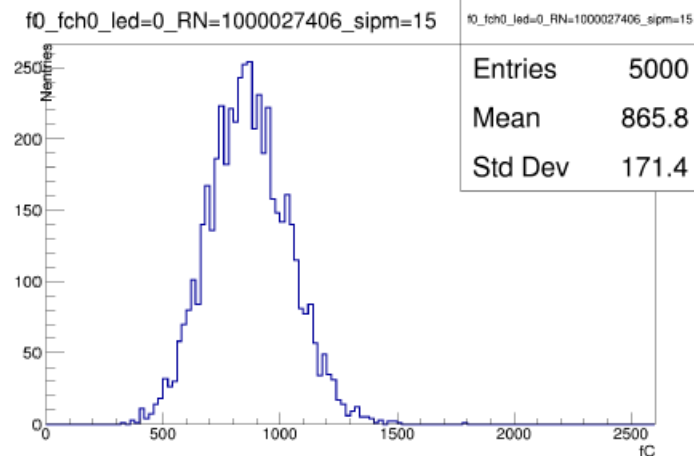
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Low intensity LED spectrum

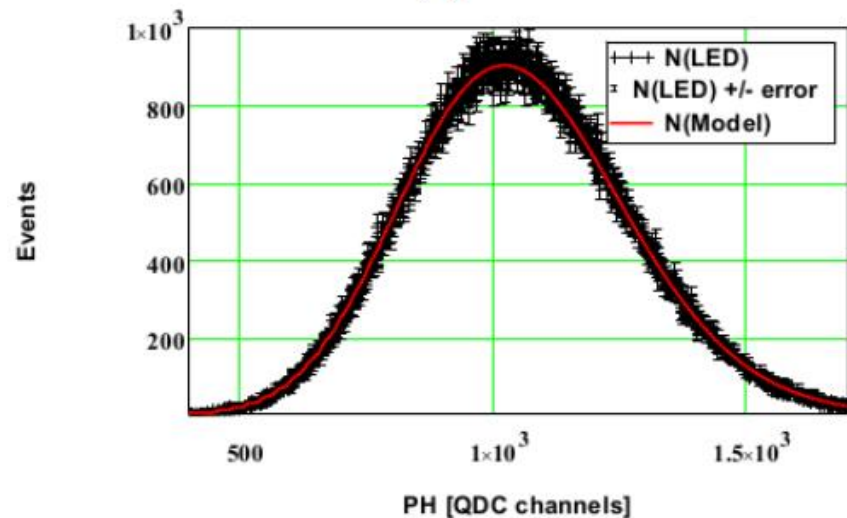


(b)



High intensity LED spectrum Pavel

P. Parygin et al., CMS meeting, Varna 2017



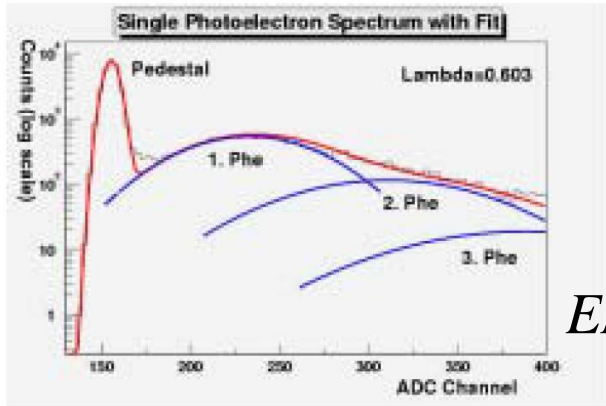
V. Chmill et al., NIMA 2017

# 2. High ENF / Low Gain

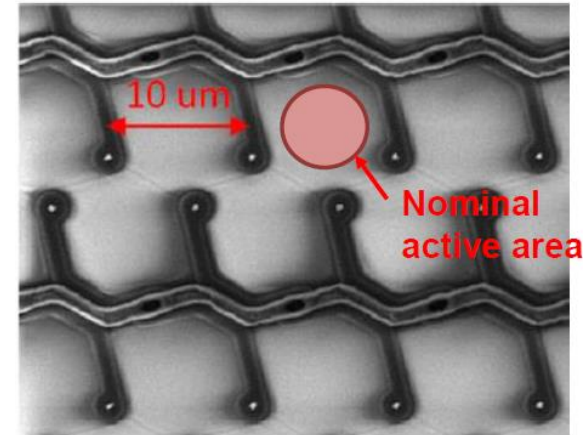


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- Excess Noise Factor (ENF) is a measure of SNR degradation due to multiplication process with random gain



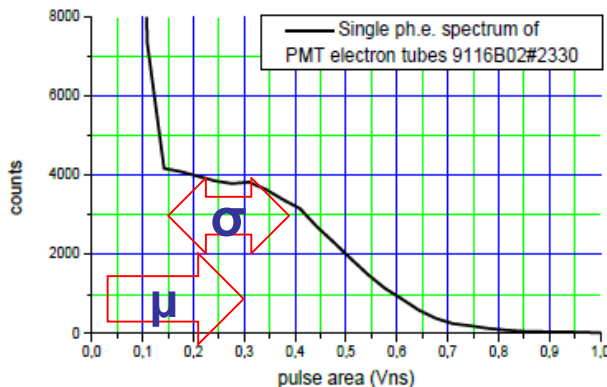
$$ENF_{Gain} = 1 + \frac{\sigma_{Gain}^2}{Gain^2}$$



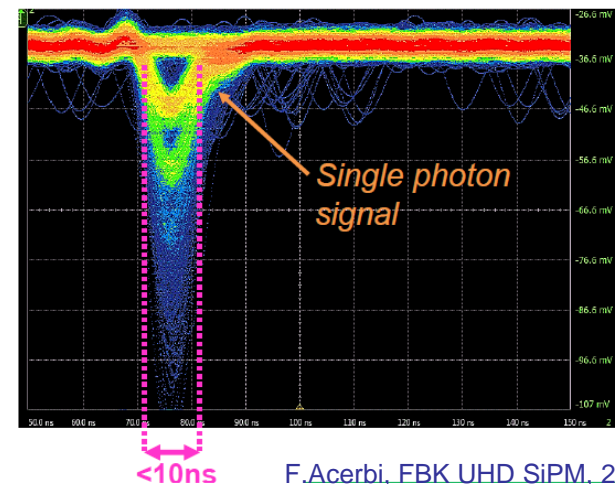
C. Hsu et al, PMT Characterization for MAGIC II Telescope, ICRS 2007

$$Gain_{SiPM} = C \cdot (V - V_{br})$$

7.5 μm cell



R. Mirzoyan: SER of low gain PMT for MAGIC (Gain ~2·10<sup>4</sup>)



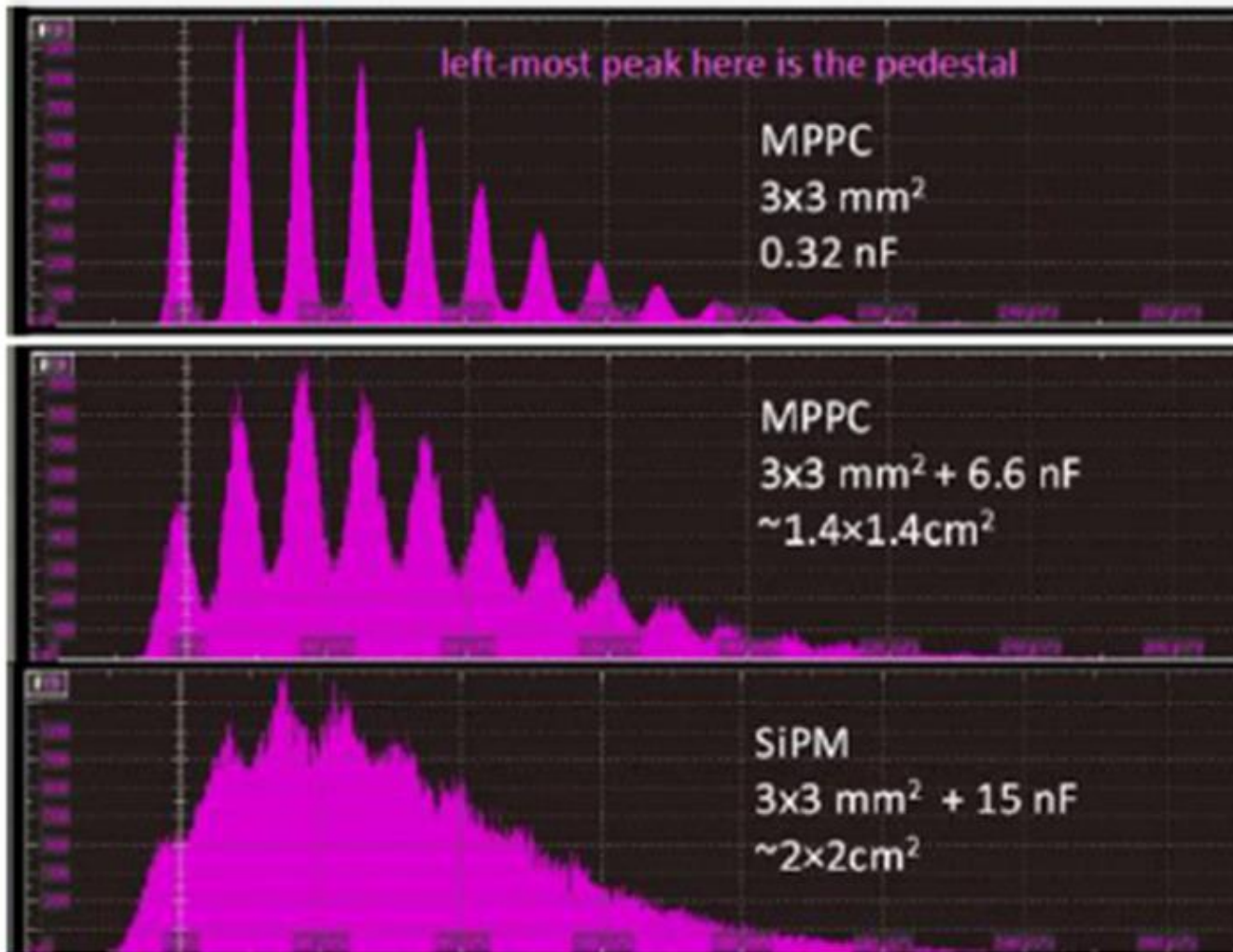
F. Acerbi, FBK UHD SiPM, 2017



### 3. Large area / High noise



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G. Visser (Indiana Univ.)

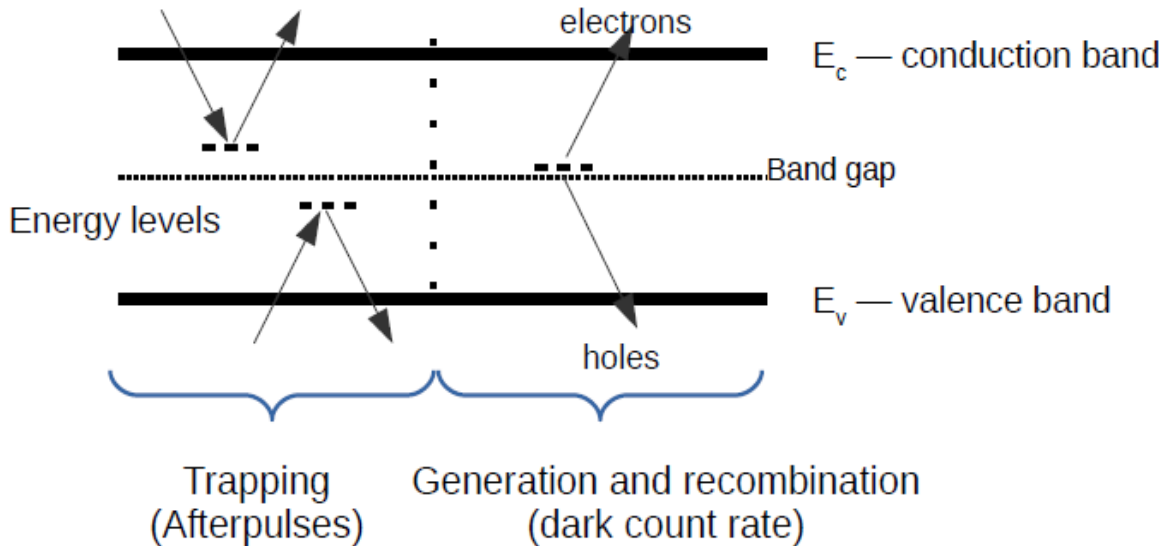
Large area SiPM (imitation by external Capacitance)

# 4. Radiation damage of SiPM

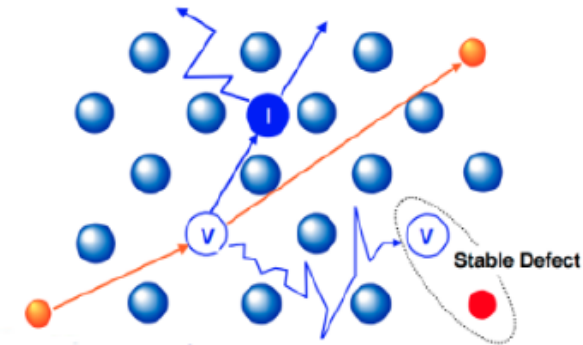


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Energy levels of radiation defects in bandgap:



Formation of defects:



Radiation defects produce energy levels in bandgap. These levels may work as trap levels or generation-recombination levels:

- Trapping levels can capture electrons or holes during avalanche and release them later. This can cause additional avalanche and additional firing of cells;
- Generation and recombination levels provide probability to generate a pair of free hole and electron (generation process) or eliminate electron and hole captured from conduction and valence bands.

Afterpulsing will increase total number of correlated events.

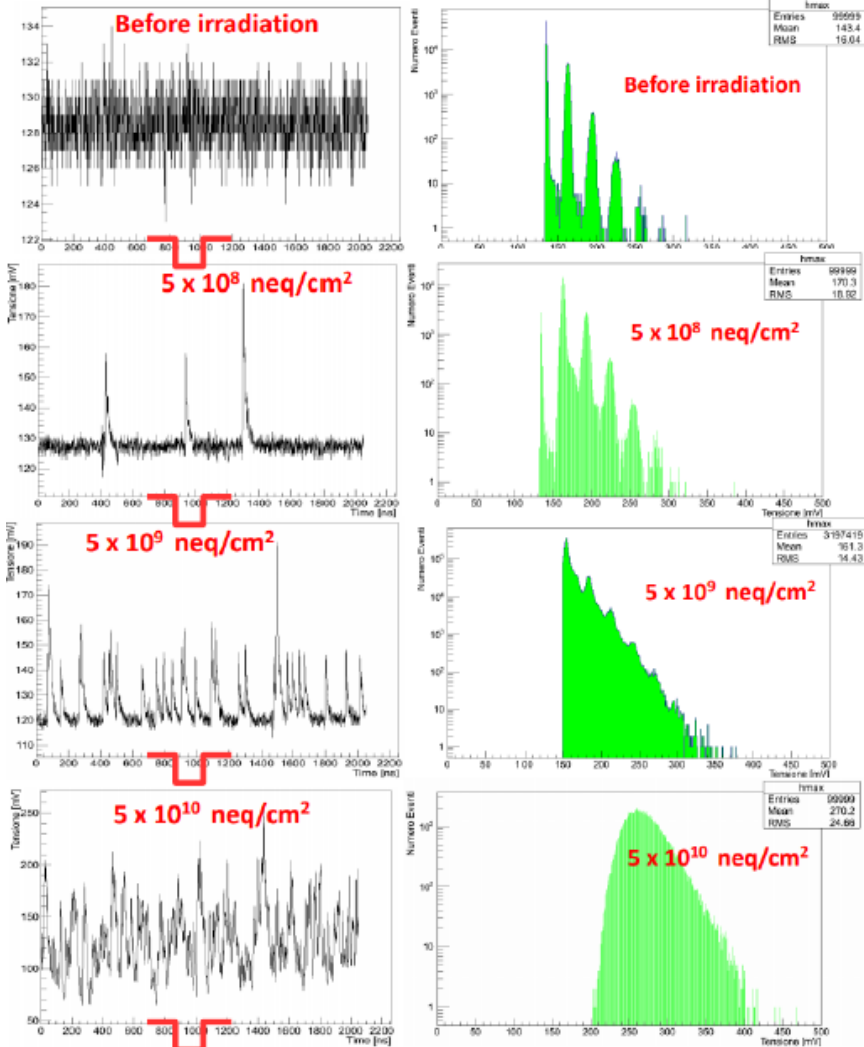
Pavel Parygin, Varna, 30th August 2017



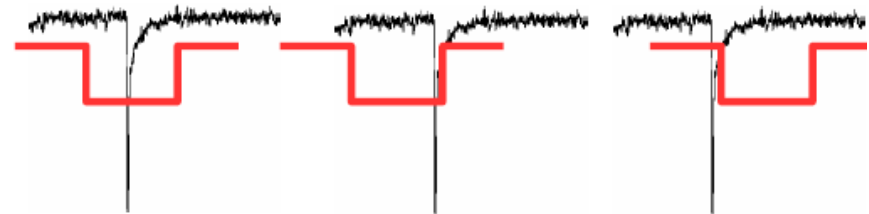
# 4. Radiation damage / High DCR / Night Sky



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Partially integrated pulses cause blurring of spectr.  
Increase of DCR will increase degradation of spectra.



Expected fluences in HCAL in Phase 1 upgrade:

- HE — up to  $10^{11}$  neq/cm<sup>2</sup>;
- HF — up to  $10^{12}$  neq/cm<sup>2</sup>;

For HGCAL expected fluence is up to  $5 \cdot 10^{13}$  neq/cm<sup>2</sup>.

Increasing of DCR leads to loss of SPE peaks.

1x1 mm<sup>2</sup>, 50 um pixel size

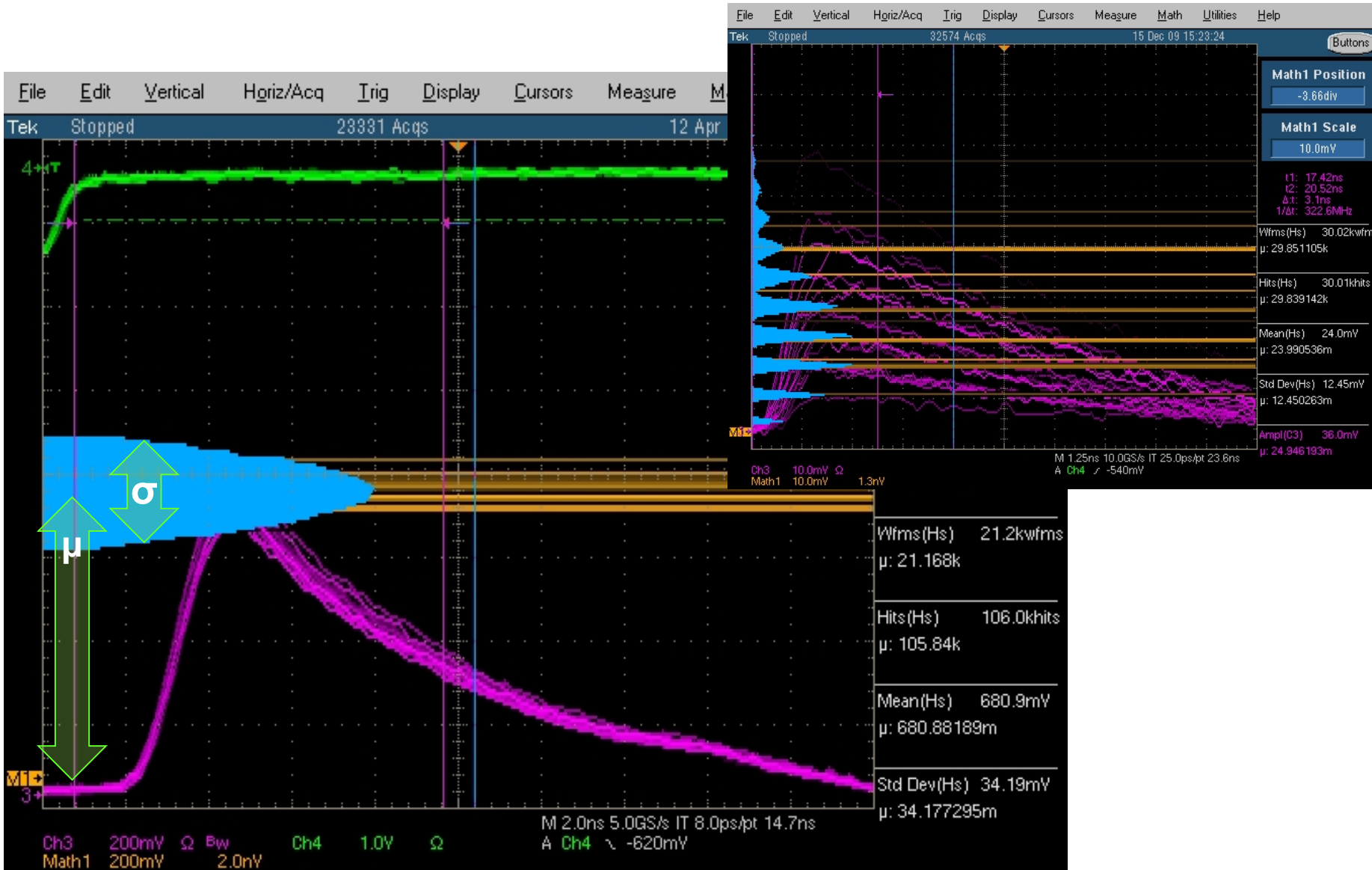
Pavel Parygin, Varna, 30th August 2017

Wander Baldini, TIPP 2014 Amsterdam, June 2-6 2014

# What we can do with unresolved spectrum?



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# SiPM response: Mean and StdDev with correlated events (CT & AP)



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$N_{pe}$ , Gain, ENF,  $Mean_{Corr}$  - unknown  
 Mean & Var =  $StdDev^2$  - measured

$$Mean_{OUT} = N_{pe} \cdot (1 + \mu_{Corr}) \cdot Gain$$

$$Var_{OUT} = N_{pe} \cdot (1 + \mu_{Corr})^2 \cdot Gain^2 \cdot ENF$$

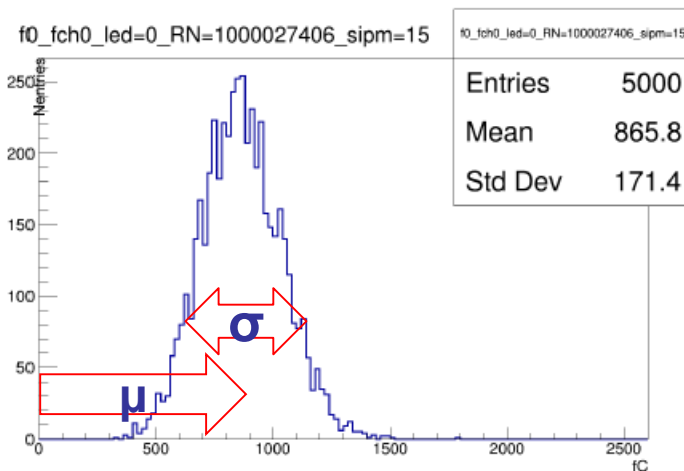
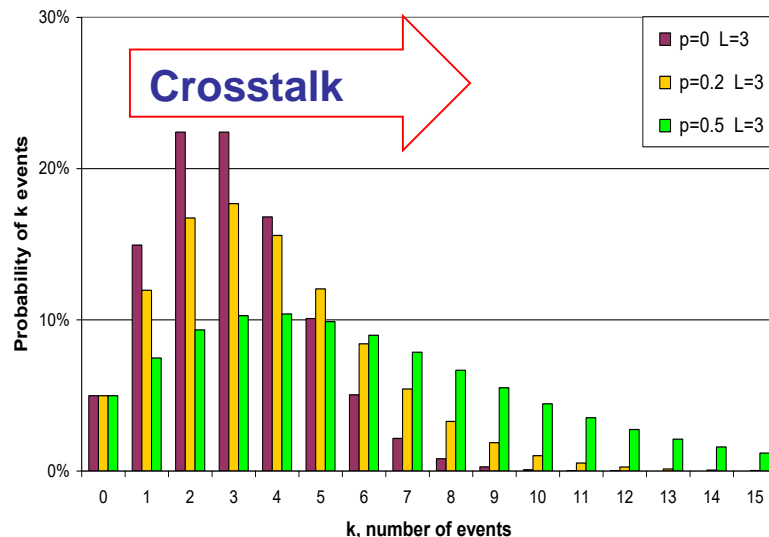
or

$$RES_{OUT} = \frac{StdDev_{OUT}}{Mean_{OUT}} = \sqrt{\frac{ENF}{N_{pe}}}$$

$$Fano_{OUT} = \frac{Var_{OUT}}{Mean_{OUT}} = Gain \cdot (1 + \mu_{Corr}) \cdot ENF$$

Unresolved spectrum =  
 = unresolved unknowns =>

**Statistics of CT & AP to be determined**



High intensity LED spectrum Pavel  
 P. Parygin et al., CMS meeting, Varna 2017

# Statistics of correlated events (CT & AP)



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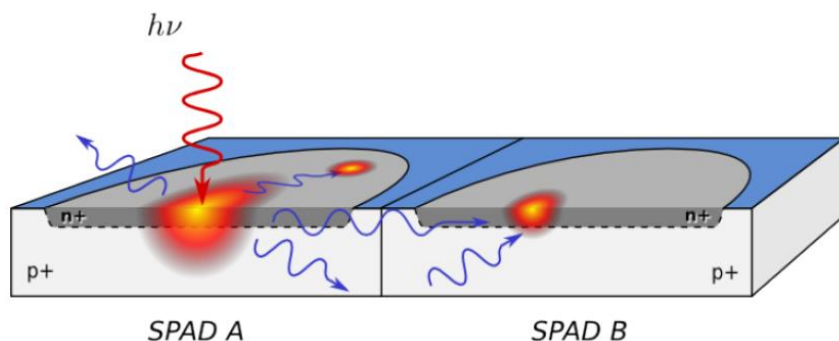
- Probability distribution of number of correlated events  $N$ 
  - ◆ Initiated by single primary event (photoelectron, dark electron)
  - ◆ Initiated by random (Poissonian) primary events
- Mean number of correlated events  $\mu_{\text{corr}}$
- StdDev of correlated events  $\sigma_{\text{corr}}$
- ENF of correlated events

$$ENF_{\text{Corr}} = 1 + \frac{\sigma_{\text{Corr}}^2}{\mu_{\text{Corr}}}$$

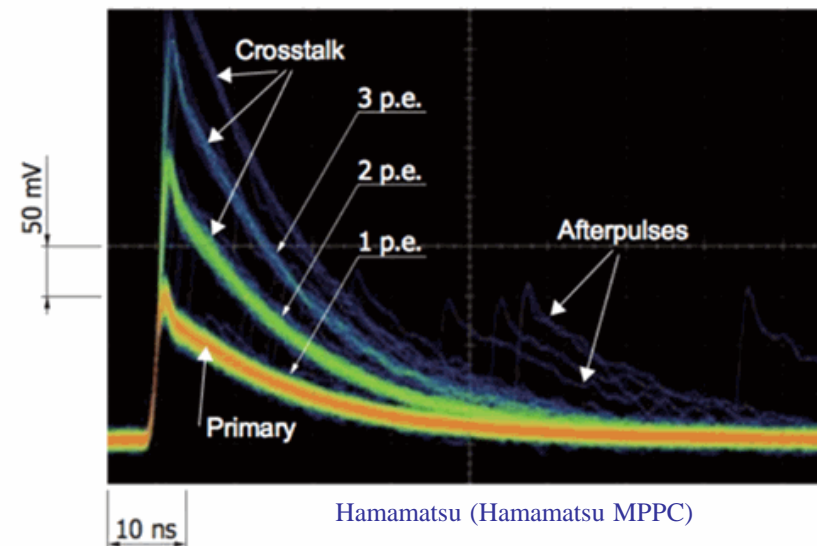
# Correlated avalanche events: SiPM crosstalk (CT) & afterpulsing (AP)



Hot carrier photon emission = CT

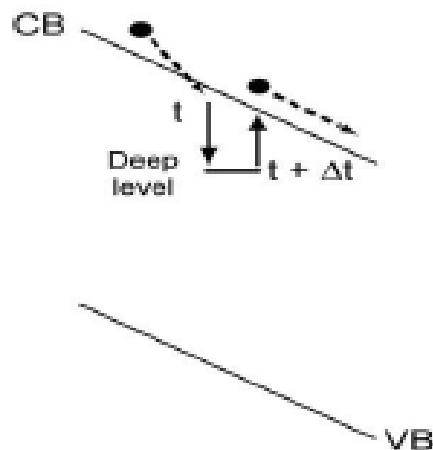


A. Lacaíta et al., IEEE TED, 1993

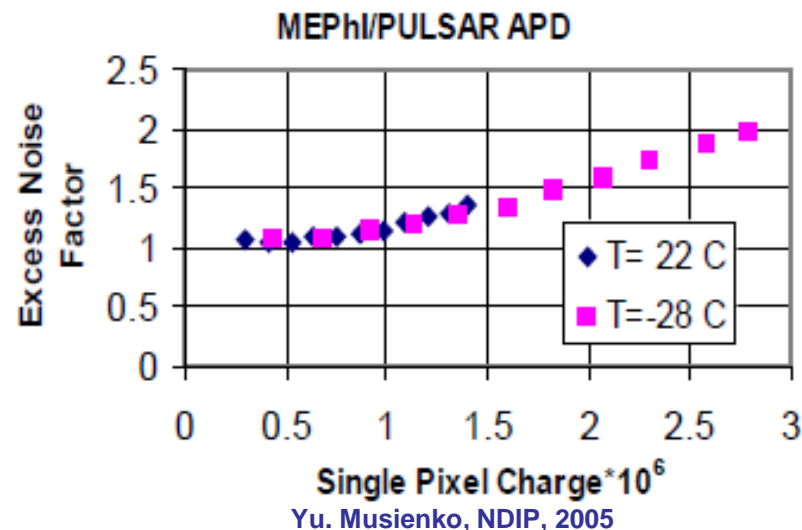


Hamamatsu (Hamamatsu MPPC)

Trapping-detrapping of carriers = AP



CT is a main contribution to ENF in SiPM



Yu. Musienko, NDIP, 2005



# Correlated stochastic processes of CT & AP



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Process Models	Single primary event $N \equiv 1$ e.g. SiPM dark electron spectrum	Poisson number of primaries $\langle N \rangle = \mu$ e.g. SiPM photoelectron spectrum
Geometric Chain Process	<p>Non-random (Dark) event</p> <p>Primary</p> <p>1<sup>st</sup> event</p> <p>2<sup>nd</sup> event</p> <p>No event</p> <p>Random AP events</p>	<p>Random primary (Photo) events</p> <p>Random AP events</p>
Branching Poisson Process	<p>Non-random (Dark) event</p> <p>Random CT events</p> <p><math>\lambda</math></p>	<p>Random primary (Photo) events</p> <p>Random CT events</p> <p><math>\mu</math></p>

S. Vinogradov, IEEE NSS/MIC 2009, TNS 2011, NDIP 2011, NIMA 2012

# Correlated process models



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<b>Results</b>	<b>Geometric chain process</b>		<b>Branching Poisson process</b>	
	Non-random single ( $N=1$ )	Poisson ( $\mu$ )	Non-random single ( $N=1$ )	Poisson ( $\mu$ )
Primary event distribution	Non-random single ( $N=1$ )	Poisson ( $\mu$ )	Non-random single ( $N=1$ )	Poisson ( $\mu$ )
Total event distribution	Geometric ( $p$ )	Compound Poisson ( $\mu, p$ )	Borel ( $\lambda$ )	Generalized Poisson ( $\mu, \lambda$ )
$P(X=k)$	$p^{k-1} \cdot (1-p)$	Ref. [1]	$\frac{(\lambda \cdot k)^{k-1} \cdot \exp(-k \cdot \lambda)}{k!}$	$\frac{\mu \cdot (\mu + \lambda \cdot k)^{k-1} \cdot \exp(-\mu - k \cdot \lambda)}{k!}$
$E[X]$	$\frac{1}{1-p}$	$\frac{\mu}{1-p}$	$\frac{1}{1-\lambda}$	$\frac{\mu}{1-\lambda}$
$Var[X]$	$\frac{p}{(1-p)^2}$	$\frac{\mu \cdot (1+p)}{(1-p)^2}$	$\frac{\lambda}{(1-\lambda)^3}$	$\frac{\mu}{(1-\lambda)^3}$
$ENF$	$1+p$		$\frac{1}{1-\lambda} \approx 1 + p + \frac{3}{2}p^2 + o(p^3) \dots$	

[1] S. Vinogradov et al., NSS/MIC 2009

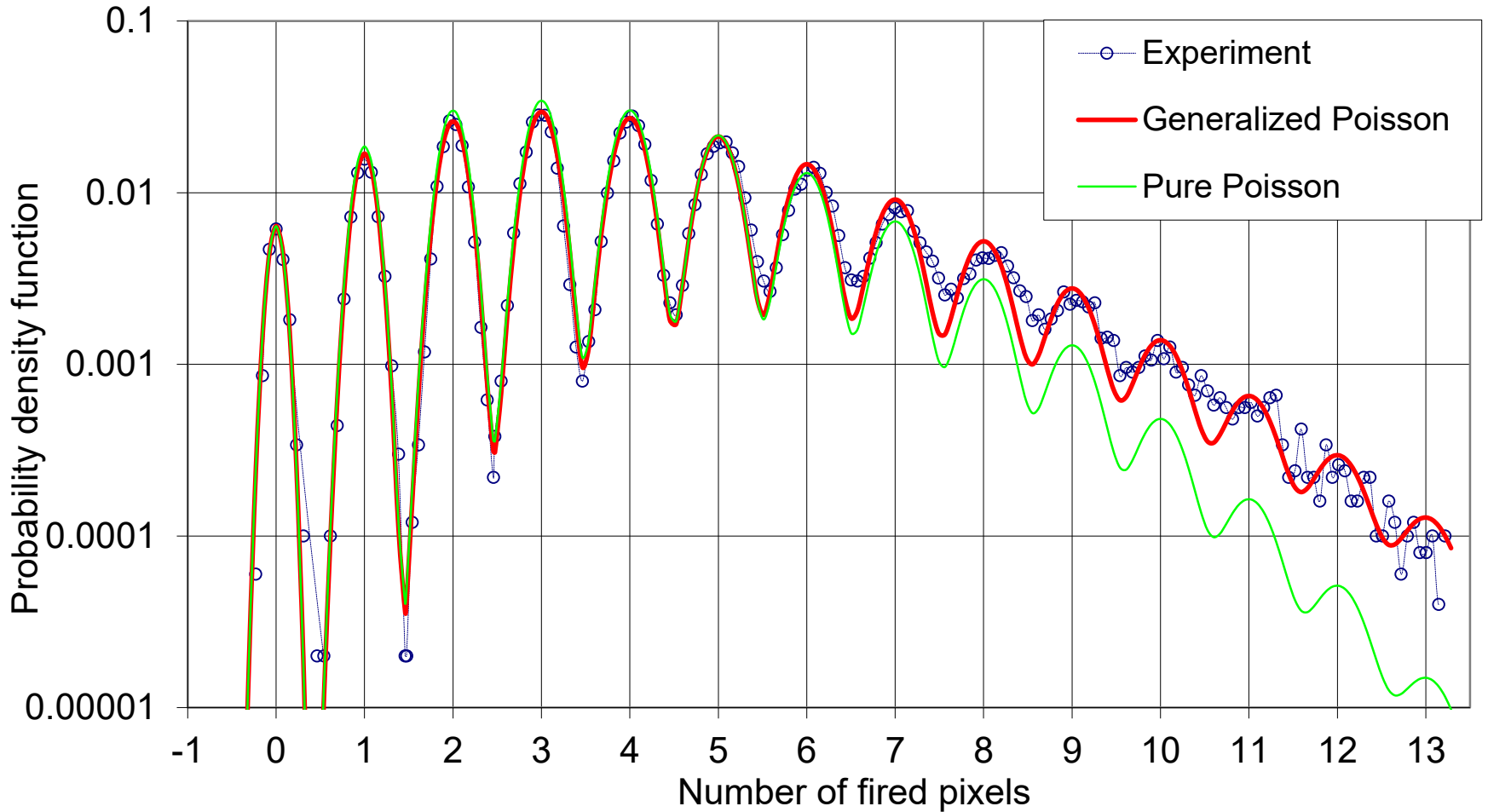
$\lambda$  is a mean number of successors in one branch generation

S. Vinogradov, IEEE NSS/MIC 2009, TNS 2011, NDIP 2011, NIMA 2012

# Generalized Poisson (branching CT) model



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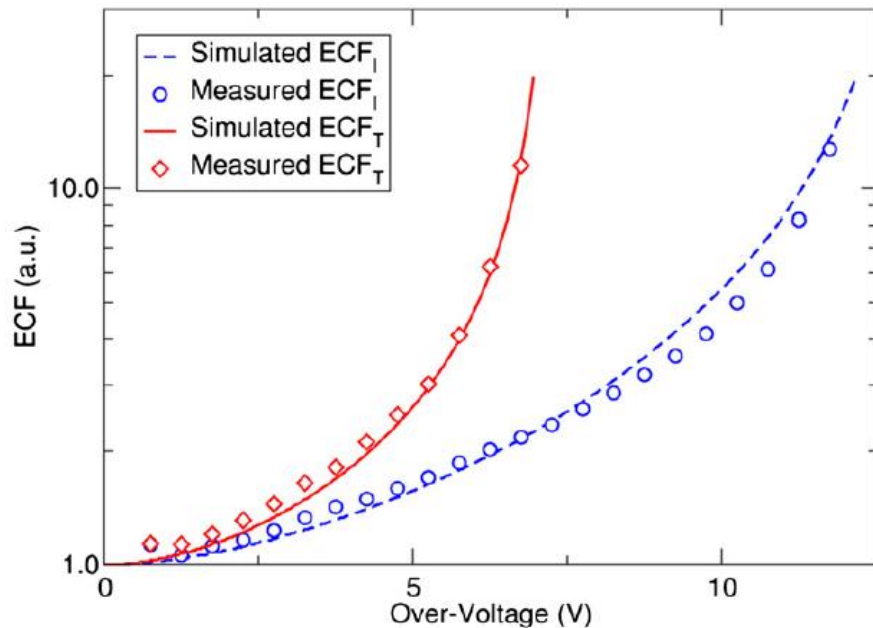
A few photon detection spectrum of Hamamatsu MPPC (S. Vinogradov, NDIP-2011, SPIE-2012)

# FBK results on Generalized Poisson model



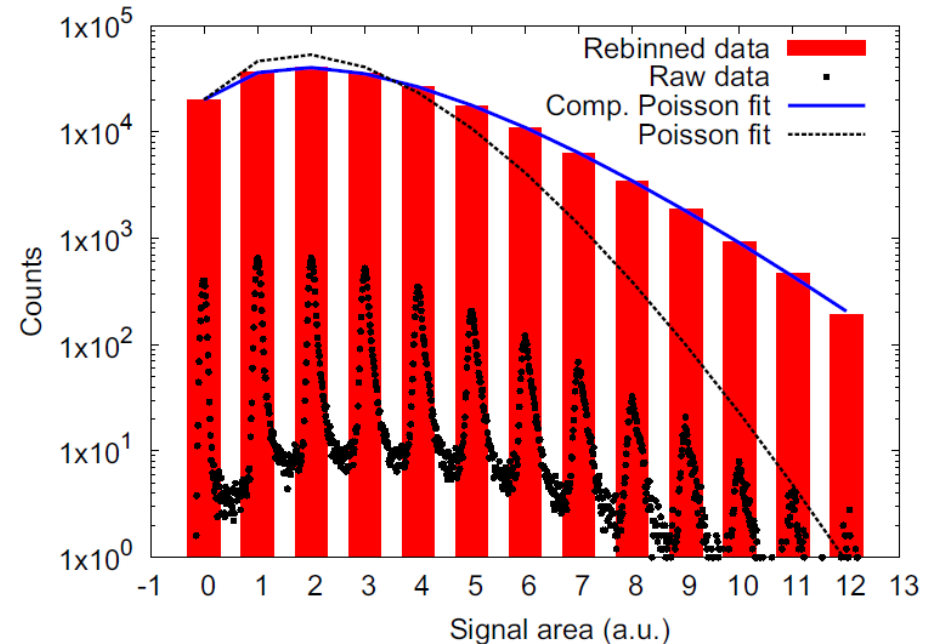
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$$\text{ENF} = \frac{1}{(1 - \gamma)} = \text{ECF}. \quad (7)$$



**Figure 5.** Comparison between the simulated and measured values of ECF for the internal and for the total (internal + external) crosstalk.

A. Gola, A. Ferri, A. Tarolli, N. Zorzi, and C. Piemonte, "SiPM optical crosstalk amplification due to scintillator crystal: effects on timing performance," *Phys. Med. Biol.*, vol. 59, no. 13, p. 3615, 2014.



**Fig. 8.** Histogram of the signal area of a  $50 \times 50\text{-}\mu\text{m}^2$  RGB SiPM excited with short and faint light pulses. Measurement conditions:  $T = 20\text{ }^\circ\text{C}$ ;  $V_{OV} = 3\text{ V}$ .

# DESY results on Generalized Poisson

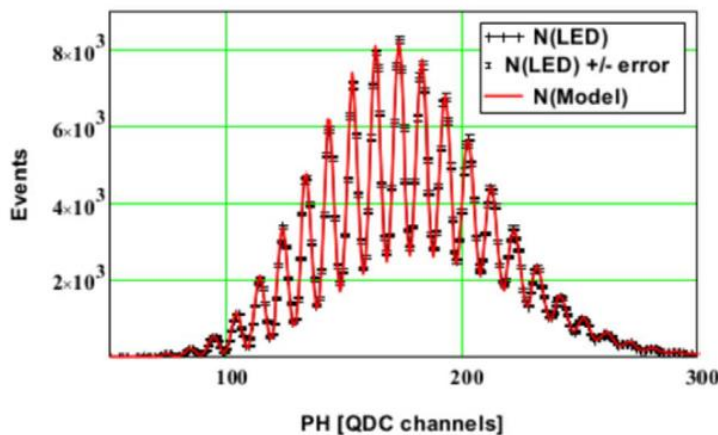


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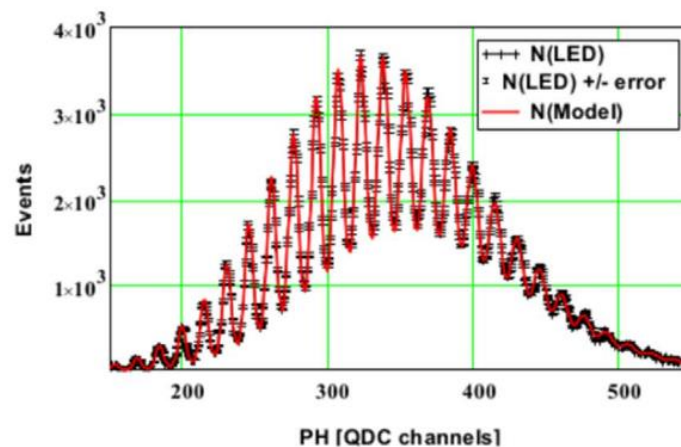
## □ E. Garutti group @ DESY: V. Chmill et al., NIMA 2017

V. Chmill et al.

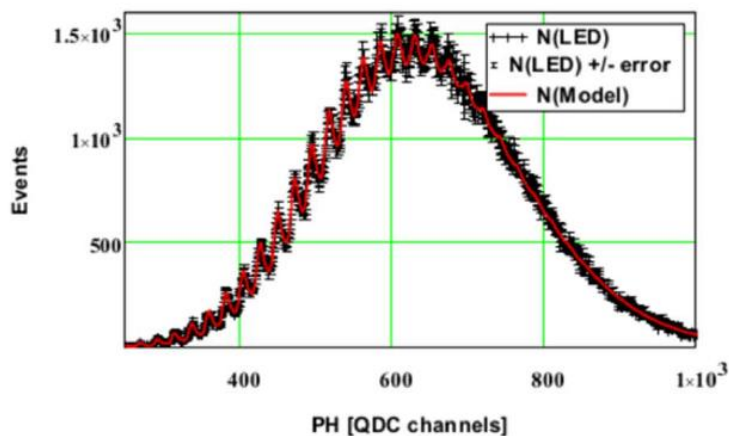
Nuclear Instruments and Methods in Physics Research A 854 (2017)



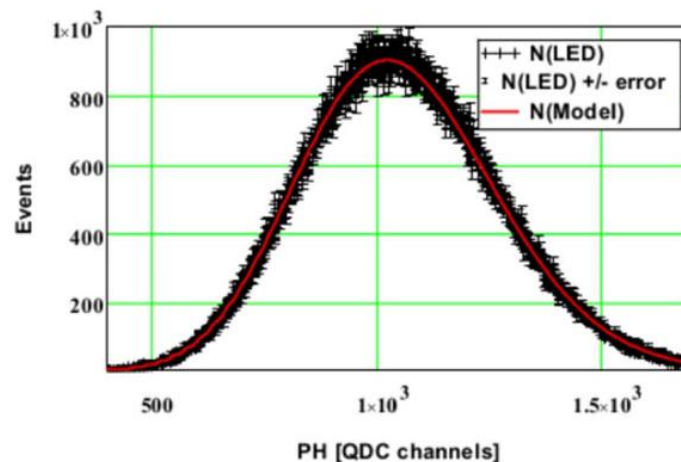
(a)



(b)



(c)



(d)



# CERN CMS results on Generalized Poisson

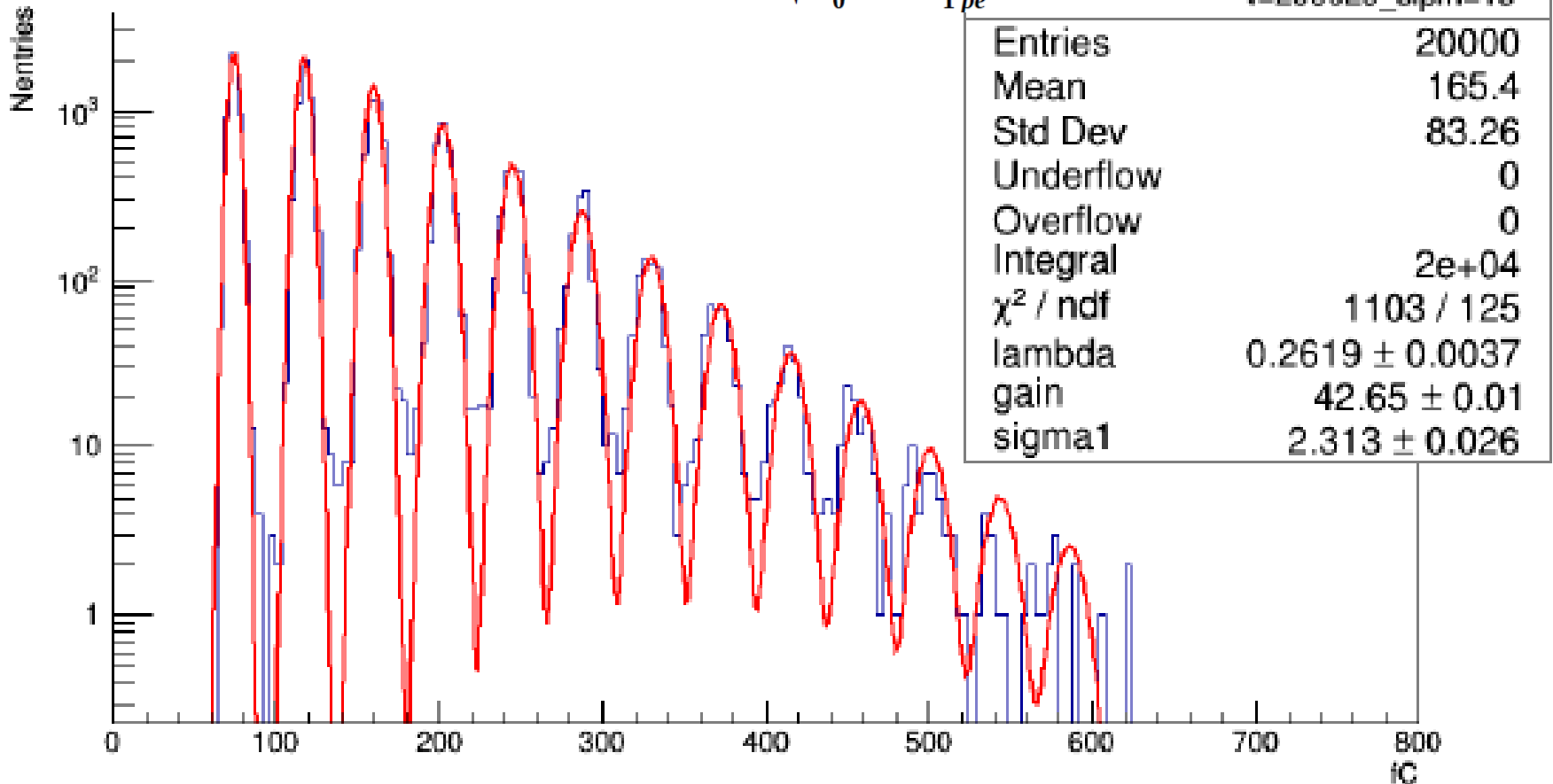


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$$G_k(\mu, \lambda) = \frac{\mu * (\mu + k * \lambda)^{k-1} * e^{-(\mu + k * \lambda)}}{k!} \quad \text{-- Generalized Poisson}$$

$$G_0(\mu, \lambda) = e^{-\mu} \quad \text{-- for 0 peak}$$

$$FF_{\lambda, gain, \sigma_{1pe}} = \sum_{k=0}^n N_{all} * BW * GP_{k, \mu, \lambda} * \frac{1}{\sqrt{2\pi} * \sqrt{\sigma_0^2 + k * \sigma_{1pe}^2}} e^{-\frac{(x - (\mu_0 + k * gain))^2}{2(\sigma_0^2 + k * \sigma_{1pe}^2)}}$$

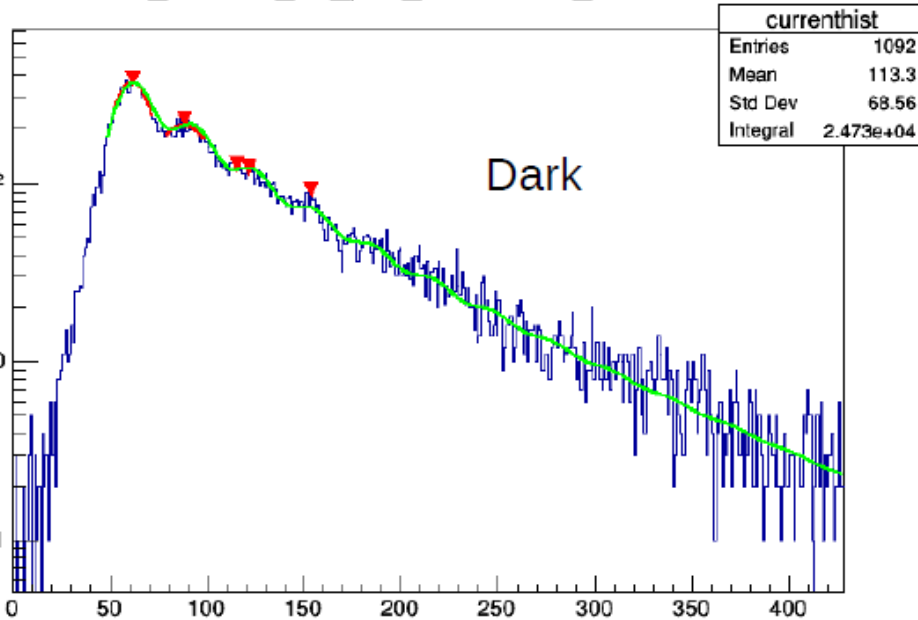


# CERN CMS results on Generalized Poisson with blurred spectra due to background light

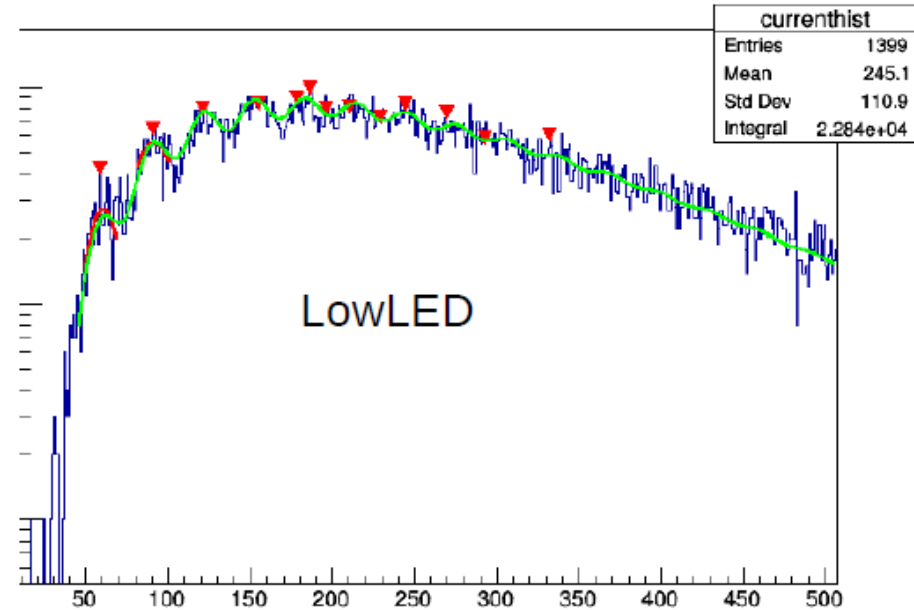


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run\_211910\_01\_ped\_SiPM=702\_BV=72.400



run\_211910\_01\_led\_SiPM=702\_BV=72.400



Pavel Parygin, Varna, 30th August 2017

20

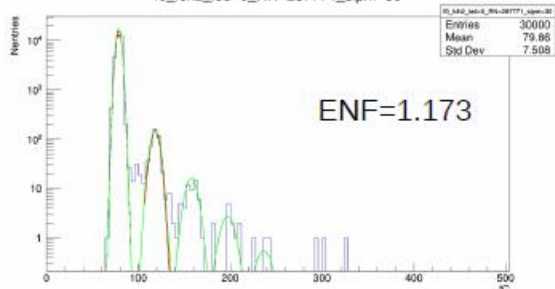
# CERN CMS results on Generalized Poisson in a progress of radiation degradation



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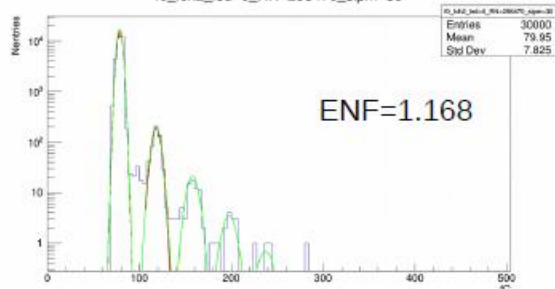
17.02.17 — 0 fb<sup>-1</sup>

f0\_fch2\_led=0\_RN=287771\_sipm=30



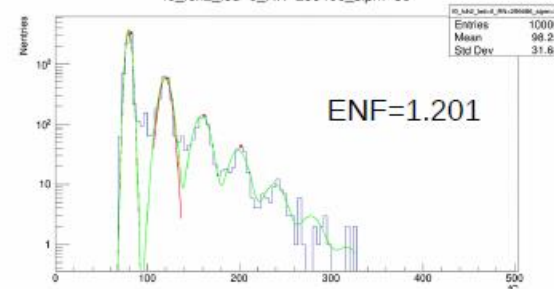
09.06.17 — 0.3 fb<sup>-1</sup>

f0\_fch2\_led=0\_RN=296470\_sipm=30



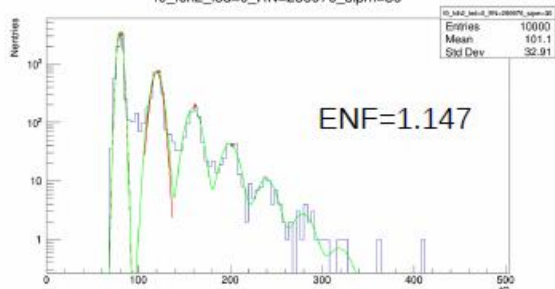
20.07.17 — 8.4 fb<sup>-1</sup>

f0\_fch2\_led=0\_RN=299466\_sipm=30



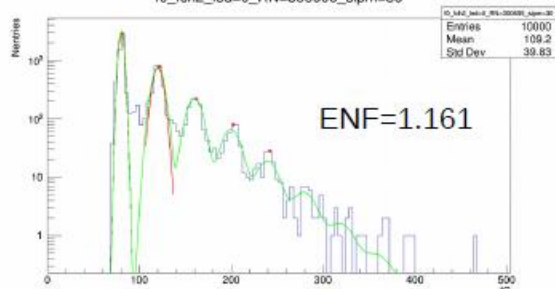
27.07.17 — 9.1 fb<sup>-1</sup>

f0\_fch2\_led=0\_RN=299976\_sipm=30



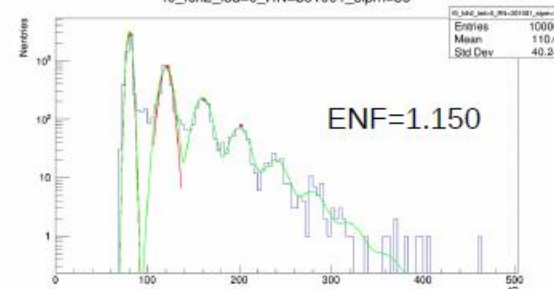
07.08.17 — 14.4 fb<sup>-1</sup>

f0\_fch2\_led=0\_RN=300605\_sipm=30



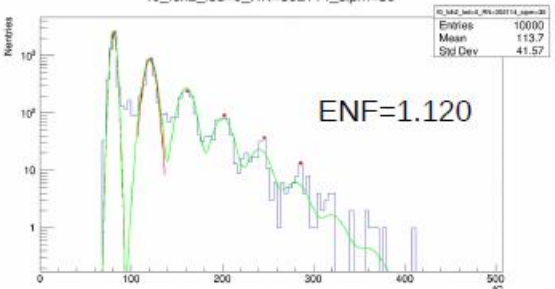
11.08.17 — 15.5 fb<sup>-1</sup>

f0\_fch2\_led=0\_RN=301001\_sipm=30



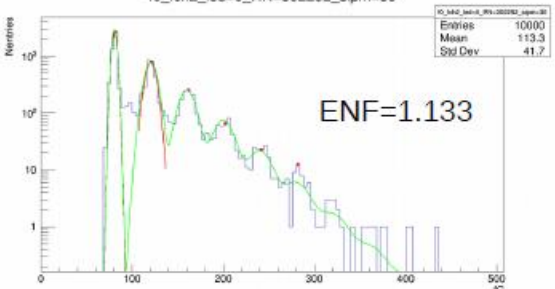
31.08.17 — 19.7 fb<sup>-1</sup>

f0\_fch2\_led=0\_RN=302114\_sipm=30



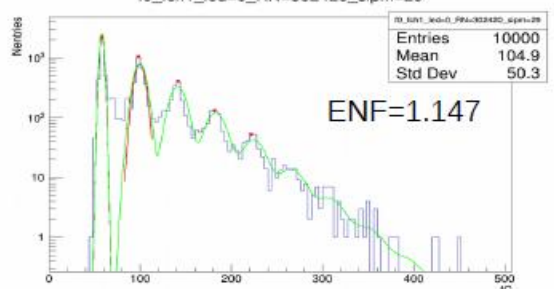
02.09.17 — 20.5 fb<sup>-1</sup>

f0\_fch2\_led=0\_RN=302252\_sipm=30



06.09.17 — 21.8 fb<sup>-1</sup>

f0\_fch1\_led=0\_RN=302420\_sipm=29



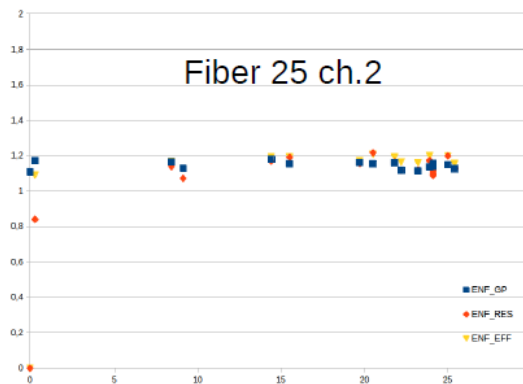
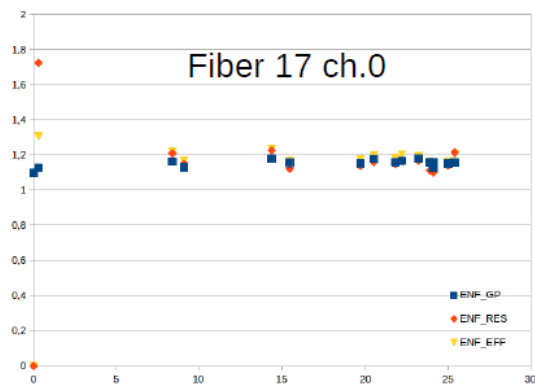
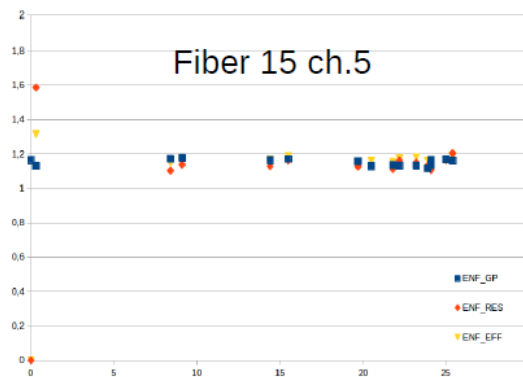
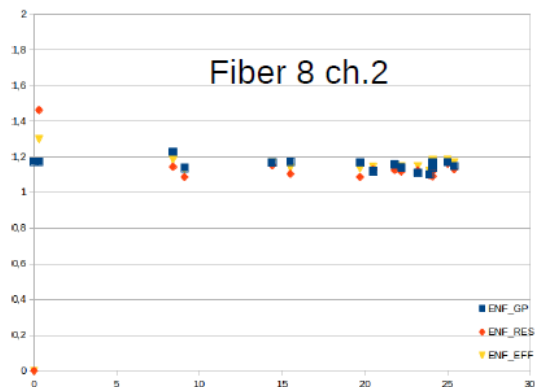
# CERN CMS results: ENF is stable and corresponds Generalized Poisson model



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Total ENF of SiPM  $\approx$  ENF of CT ( $\text{ENF}_{\text{Gain}} \approx 1.01$ )

## ENF values calculated by different methods



Comparison of the ENF values calculated by 3 methods plotted with respect to integrated luminosity

14

# Monitoring of Gain during degradation

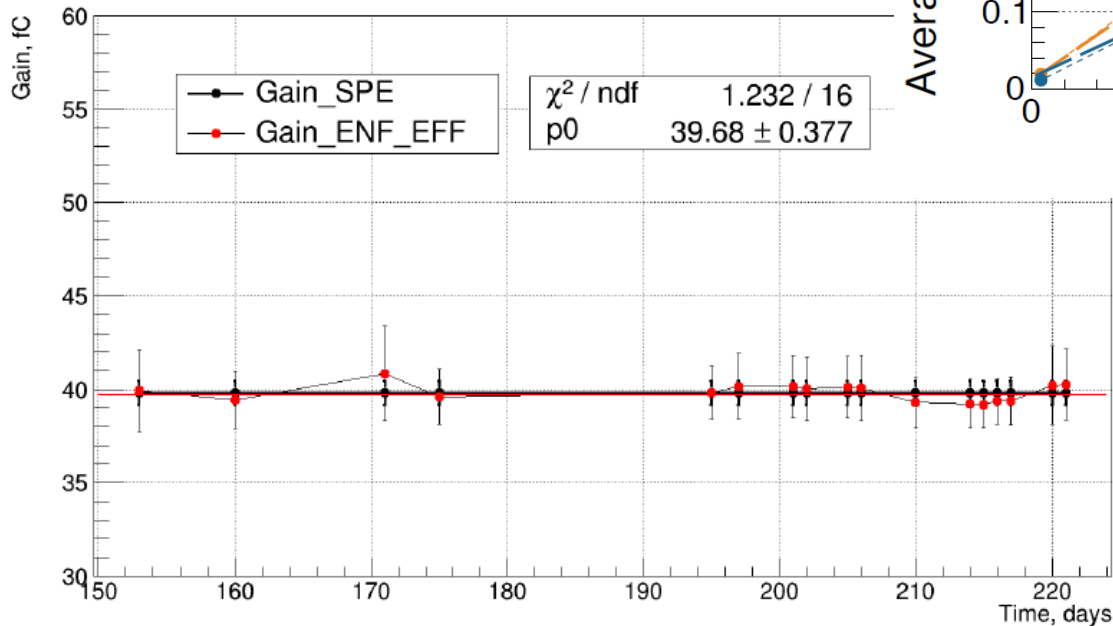


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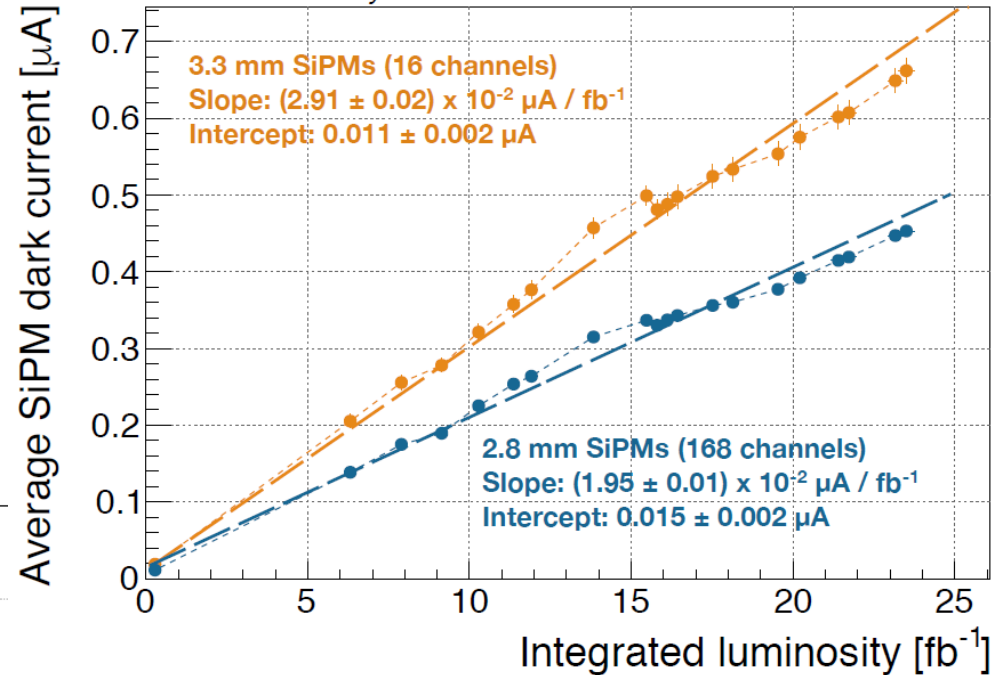
$$\text{Effective Gain} = Fano = \frac{\text{Var}_{OUT}}{\text{Mean}_{OUT}} = \text{Gain} \cdot ENF^2$$

$$\Rightarrow \text{Gain}_{ENF} = \frac{\text{Var}_{OUT}}{\text{Mean}_{OUT}} \cdot \frac{1}{ENF^2}$$

Extracted gain -vs- Time



CMS Preliminary 2017



Next question:  
How to recognize changes of  
Gain and/or ENF if something  
is unstable?



# Assumptions based on branching process model of correlated events



## Knowledge on ENF

- ◆ Total ENF of SiPM  $\approx$  ENF of CT ( $ENF_{Gain} \approx 1.01$ )
- ◆ CT branching process model:

$$ENF_{CT} = 1 + \mu_{CT} = \frac{1}{1 - \lambda} = \frac{1}{1 + \ln(1 - Pct)} \approx 1 + Pct + \frac{3}{2} Pct^2 \dots$$

$$\frac{StdDev_{OUT}}{Mean_{OUT}} = \sqrt{\frac{ENF}{N_{pe}}} \Rightarrow N_{ENF} = \frac{Mean_{OUT}^2}{Var_{OUT}} \cdot ENF$$

$$\frac{Var_{OUT}}{Mean_{OUT}} = Gain \cdot ENF^2 \Rightarrow Gain_{ENF} = \frac{Var_{OUT}}{Mean_{OUT}} \cdot \frac{1}{ENF^2}$$

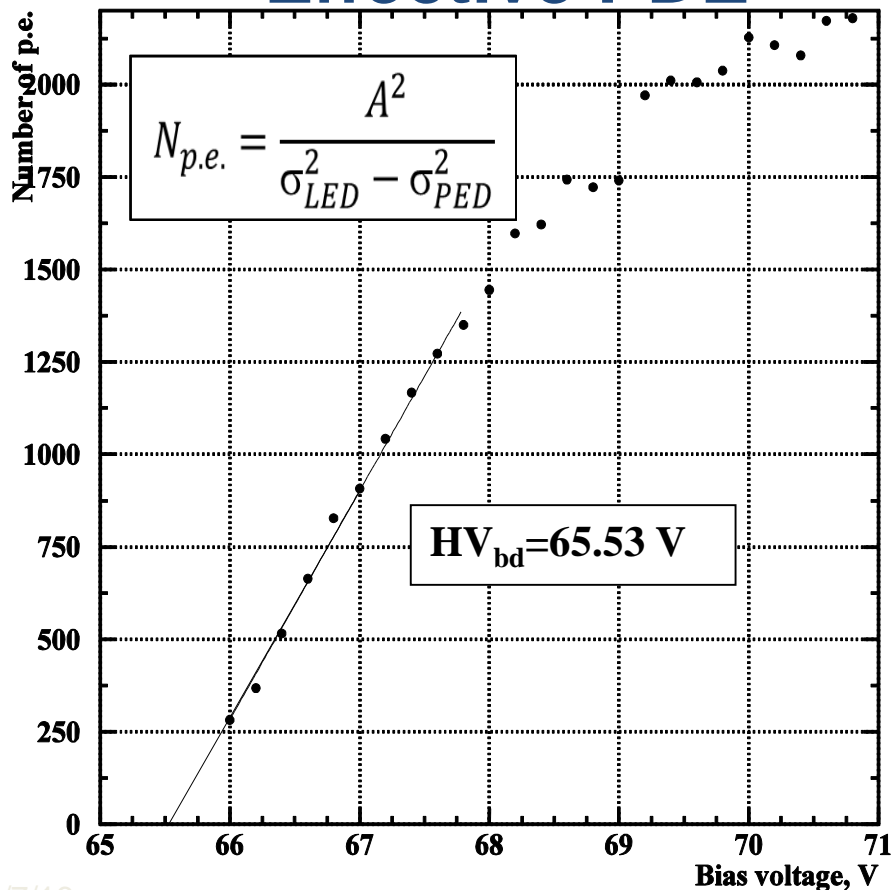
## Knowledge on Gain: linearity vs Overvoltage

$$Effective \ Gain = \frac{Var_{OUT}}{Mean_{OUT}} = Gain \cdot ENF^2 = \frac{C(V - Vbr)}{q} \cdot [ENF(V - Vbr)]^2$$

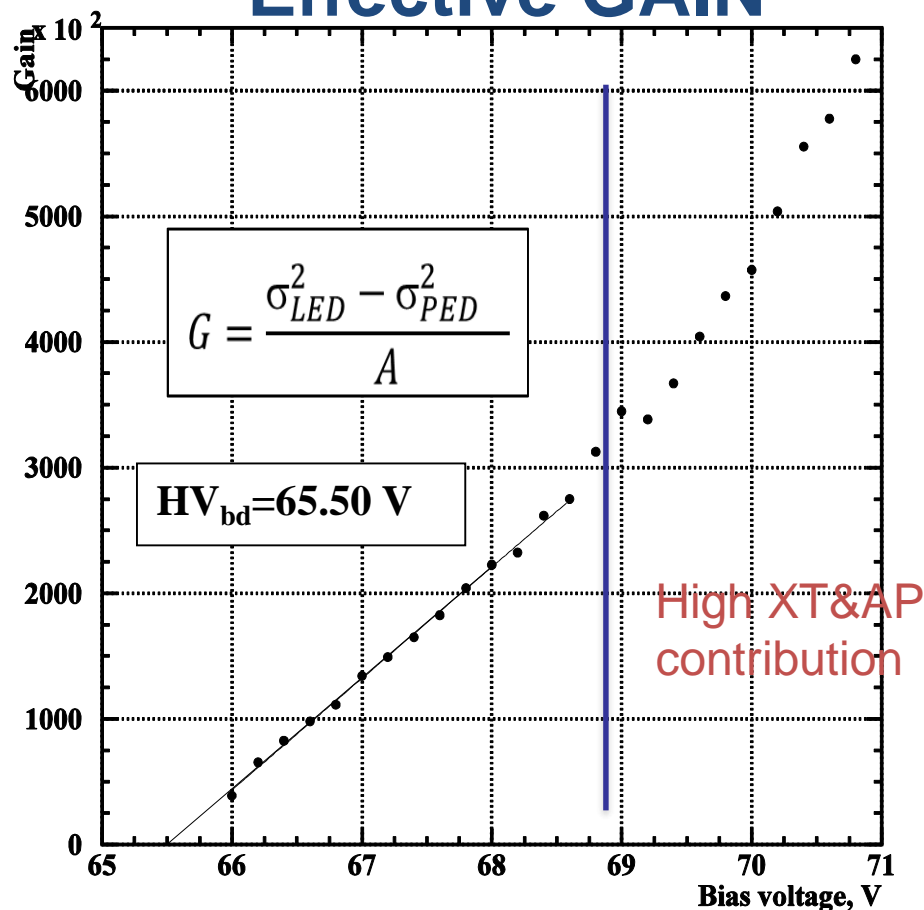
# Number of photoelectrons and gain from statistical approach for high intensity LED flashes

This procedure may be applied to SiPM's after irradiation and doesn't require IV measurements

## Effective PDE



## Effective GAIN

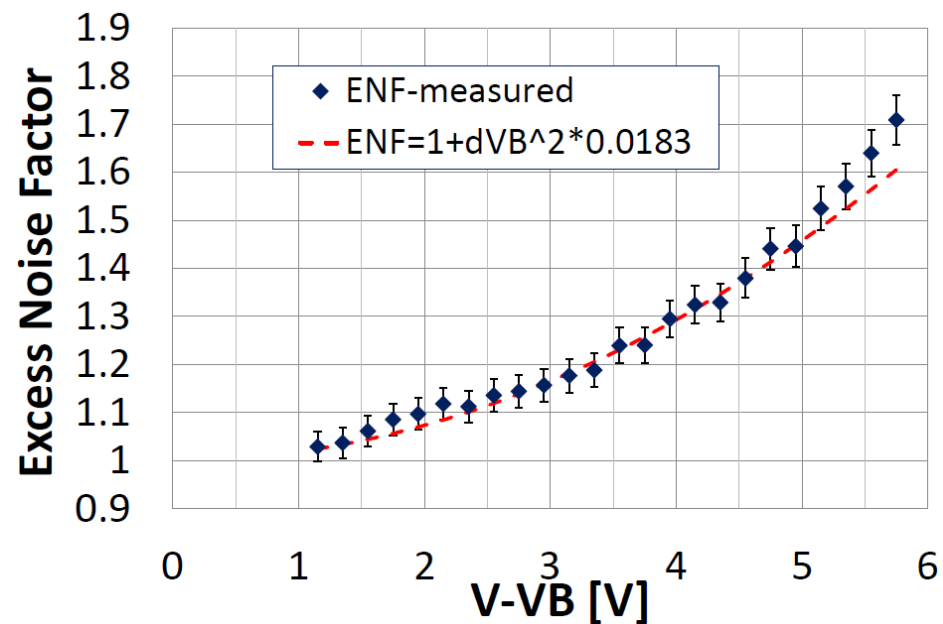
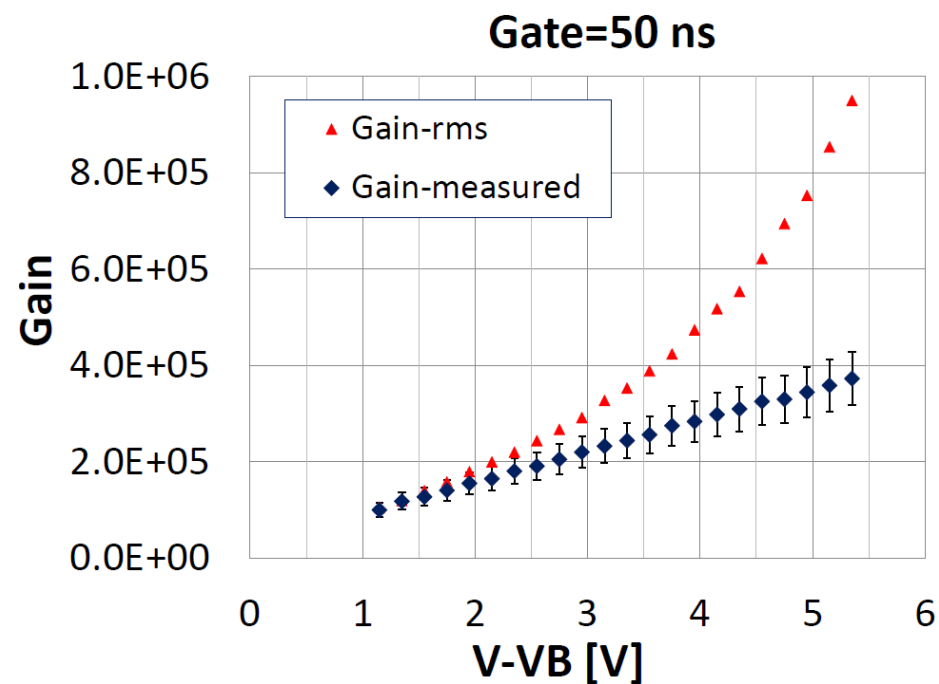


# Approach is also supported by CMS SiPM results (Yu. Musienko)



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Gain-rms = Effective Gain =  $\text{Var}/\text{Mean}$



Yu. Musienko, CERN CMS meeting on SiPM, 12-07-2017

# Summary



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- Unresolved SiPM spectra could be caused by many scenarios
- SiPM characterization in such cases is challenging, but possible
- Characterization is facilitated by Branching Poisson CT model
- Radiation-induced damage of SiPM does not affect CT (ENFct)
- Monitoring of Gain in case of known and stable ENFct is accurate and reliable by Fano factor (Effective gain) =  $\text{Var}/\text{Mean}$
- True Gain and ENF could be determined from Effective Gain due to linearity of Gain vs Voltage
  
- We are in progress to advance the GP-based characterization

# The end



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## Questions?

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# BACKUP



# Binomial model of CT



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## Modeling optical crosstalk: formulations

L. Gallego et al.  
JINST 8 (2013) P05010

**Analytical expressions** for  $P_1(k)$  and related parameters

$k$	4 nearest neighbors	8 nearest neighbors	8 L-connected neighbors	All neighbors
1	$q^4 (= 1 - \epsilon)$	$q^8 (= 1 - \epsilon)$	$q^8 (= 1 - \epsilon)$	$q^{N-1} (= 1 - \epsilon)$
2	$4pq^6$	$8pq^{14}$	$8pq^{14}$	$\binom{N-1}{1} pq^{2(N-2)}$
3	$18p^2q^8$	$12p^2q^{18} [1 + 2q + 4q^2]$	$84p^2q^{20}$	$\binom{N-1}{2} p^2 q^{3(N-3)} [1 + 2q]$
4	$4p^3q^8 [1 + 3q + 18q^2]$	$4p^3q^{20} [1 + 3q + 14q^2 + 30q^3 + 61q^4 + 59q^5 + 72q^6]$	$24p^3q^{24} [1 + 3q + 38q^2]$	$\binom{N-1}{3} p^3 q^{4(N-4)} [1 + 3q + 6q^2 + 6q^3]$
5	$5p^4q^{10} [8 + 24q + 55q^2]$	$5p^4q^{24} [9 + 36q + 98q^2 + 188q^3 + 310q^4 + 372q^5 + 520q^6 + 396q^7 + 341q^8]$	$4p^4q^{30} [180 + 540q + 2521q^2]$	$\binom{N-1}{4} p^4 q^{5(N-5)} [1 + 4q + 10q^2 + 20q^3 + 30q^4 + 36q^5 + 24q^6]$

$p$  : prob. for 1 neighbor

$q = 1-p$

$\epsilon = P_1(k > 1)$

$N$  : number pixels of the array

Geometric extrapolation for  $k > 5$

$$P_1(k) \approx P_1(5) \cdot (1-r)^{k-5}$$

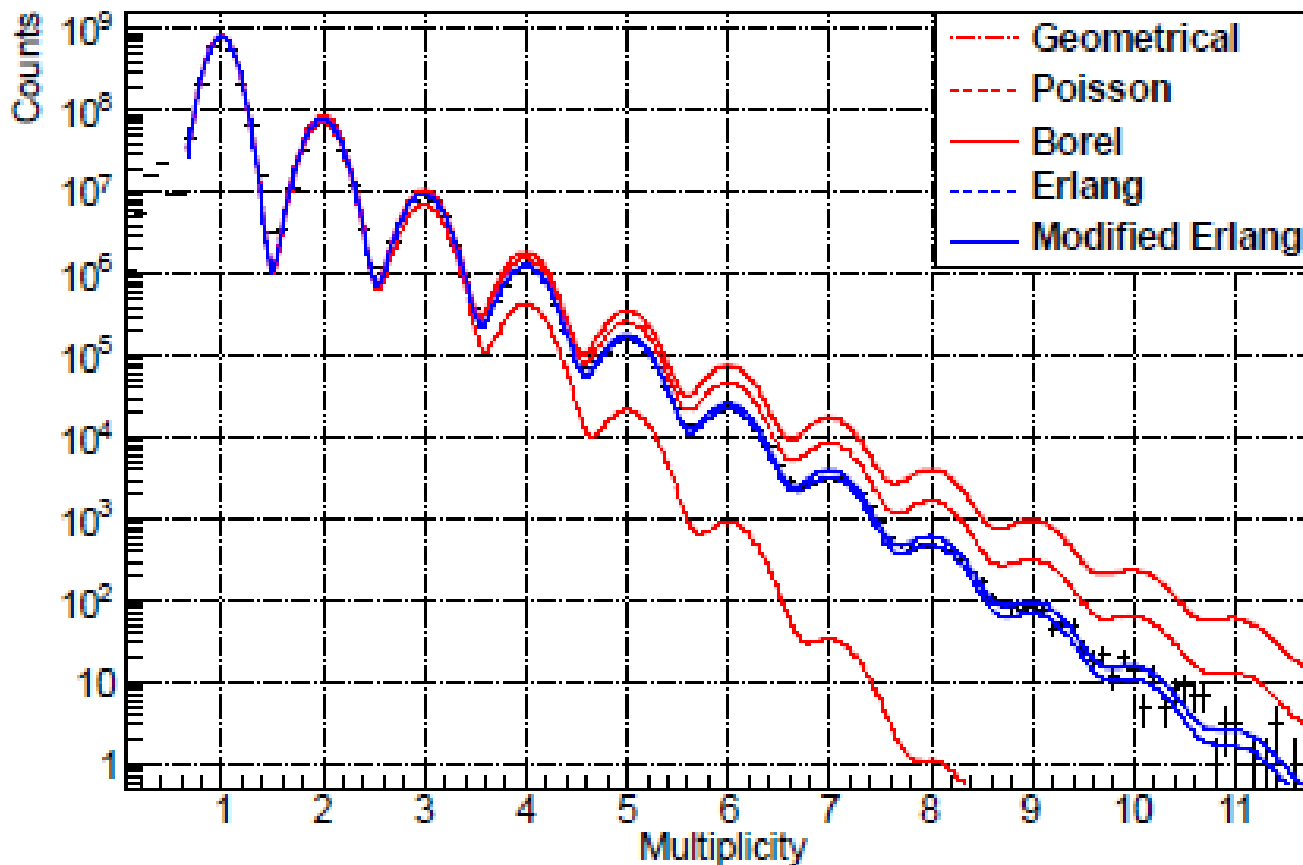
$$r = \frac{P_1(5)}{1 - \sum_{k=1}^4 P_1(k)}$$

$$E_1 \approx \sum_{k=1}^4 k \cdot P_1(k) + P_1(5) \frac{1+4r}{r^2}$$

$$\text{Var}_1 \approx \sum_{k=1}^4 k^2 \cdot P_1(k) + P_1(5) \frac{2+7r+16r^2}{r^3} - E_1^2$$

$$\text{ENF} = \frac{\sum_{k=1}^4 k^2 \cdot P_1(k) + P_1(5) \frac{2+7r+16r^2}{r^3}}{\left[ \sum_{k=1}^4 k \cdot P_1(k) + P_1(5) \frac{1+4r}{r^2} \right]^2}$$

# Erlang distribution (FACT team, 2014)



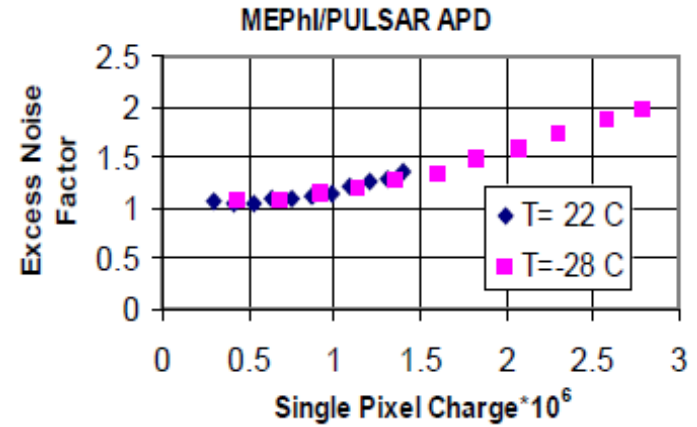
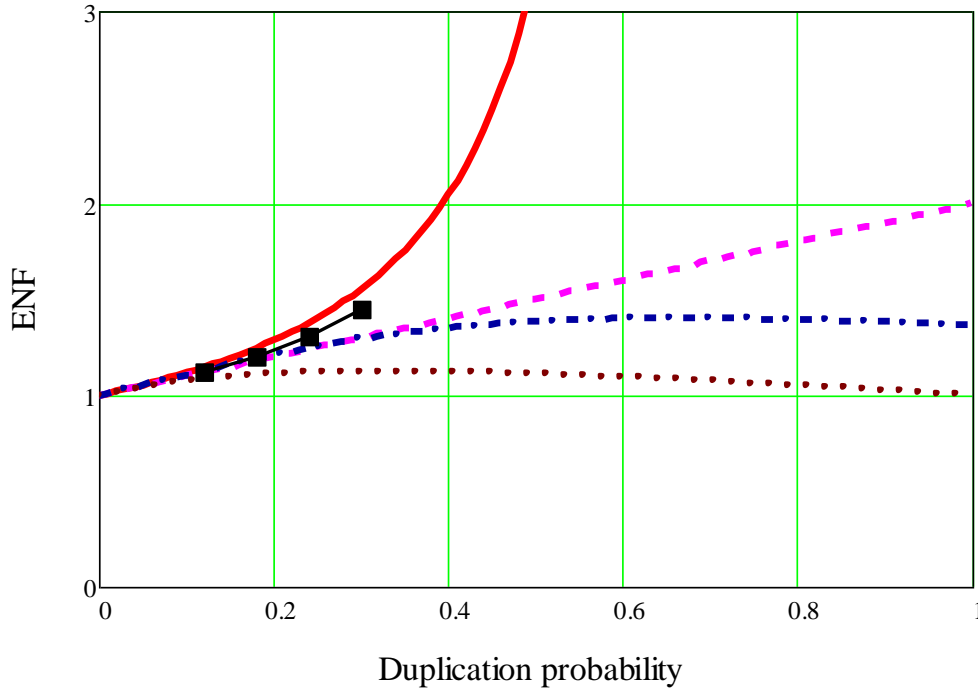
**Figure 17.** A measured single-p.e. spectrum overlaid with several different distribution function fitted to the data. The pure Poisson distribution significantly underestimates the data, while the Borel distribution clearly overestimates the data. The geometrical distribution by chance gets very close to the data. A good fit is obtained by the Erlang and modified Erlang distribution.

# CT ENF models and experiments



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Analytical models of duplication Excess Noise Factor



Yu. Musienko, NDIP, 2005

- Branching Poisson
- - - Geometric Chain
- · - · - Binomial
- · · · · Bernoulli
- Experiment

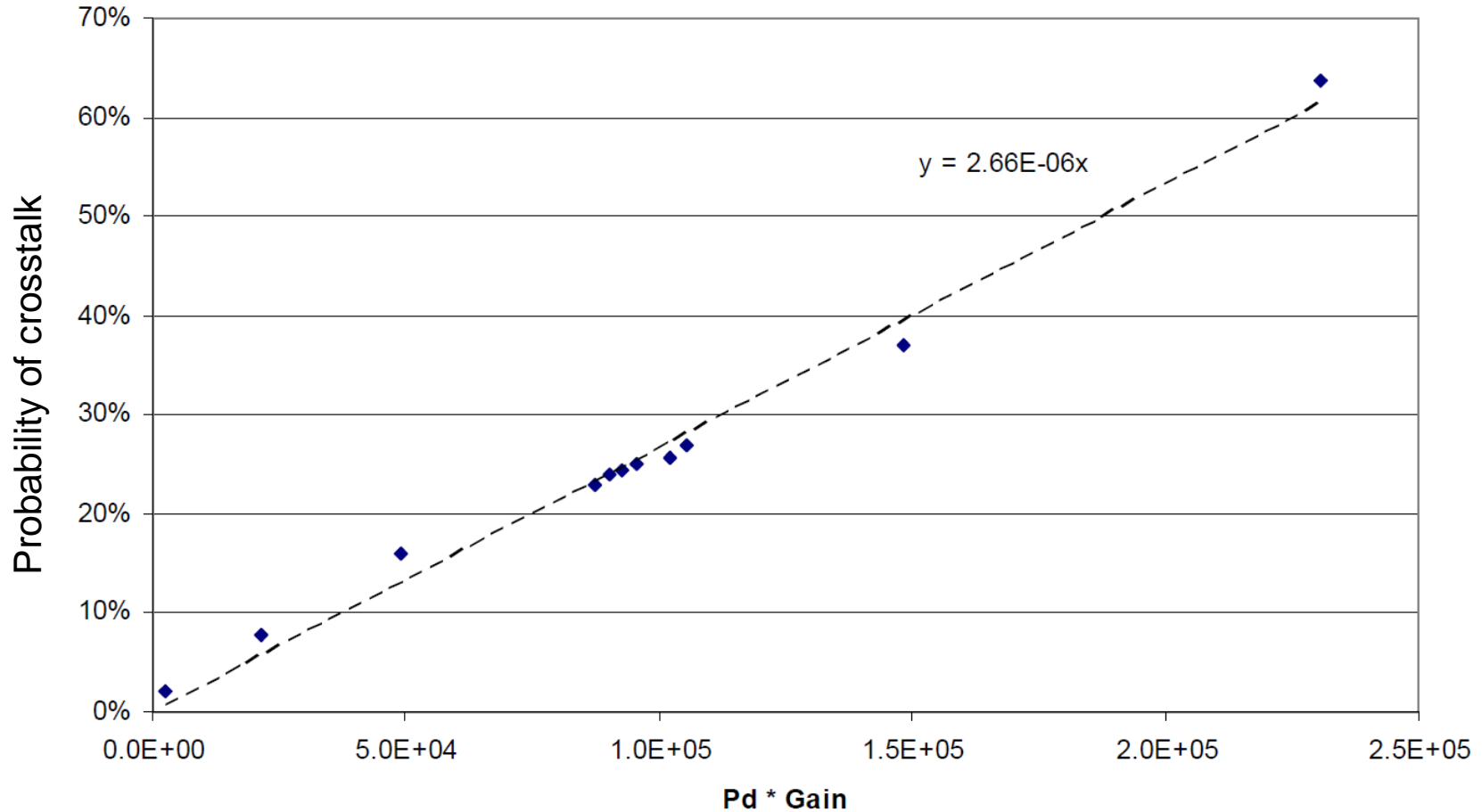
Bernoulli model: M. Ramilli et al., J. Opt. Soc. Am. B 27, 852-862 (2010)

Binomial model: L. Gallego et al., arXiv: [physics.ins-det] 2013

# Pct ~ PDE·Gain



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- K. Linga, et al., "[Solid state photomultiplier: noise parameters of photodetectors with internal discrete amplification](#)", Proc. SPIE 6119; 61190K, 2006.